# ne<mark>x</mark>peria

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Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

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Should be replaced with:

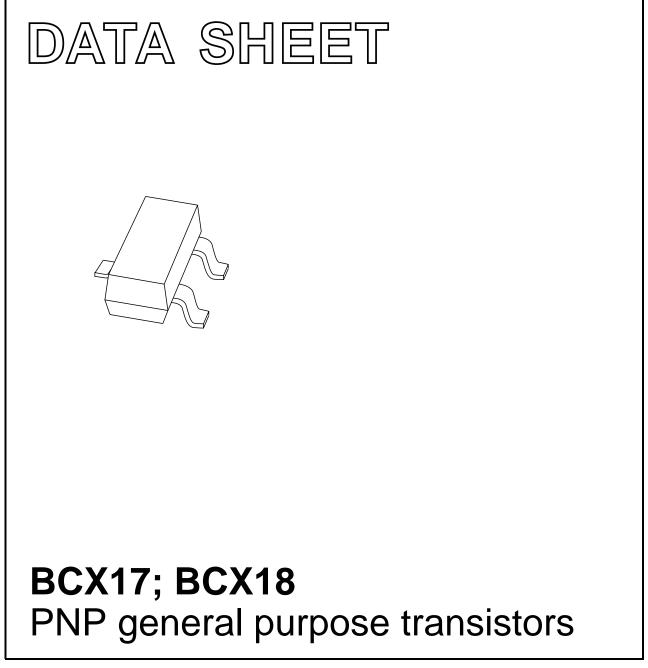
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

### DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 May 31 2004 Jan 16



### FEATURES

- High current (max. 500 mA)
- Low voltage (max. 45 V).

### APPLICATIONS

- Saturated switching and driver applications e.g. for industrial service
- Thick and thin-film circuits.

### DESCRIPTION

PNP transistor in a SOT23 plastic package. NPN complement: BCX19.

#### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BCX17	T1*
BCX18	T2*

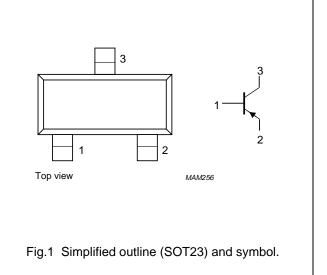
#### Note

- 1. \* = p : Made in Hong Kong.
  - \* = t : Made in Malaysia.
  - \* = W : Made in China.

### **ORDERING INFORMATION**

PINNING
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PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



TYPE	PACKAGE			
NUMBER	NAME DESCRIPTION		VERSION	
BCX17	<ul> <li>plastic surface mounted package; 3 leads</li> </ul>		SOT23	
BCX18				

### **BCX17; BCX18**

### BCX17; BCX18

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BCX17		-	-50	V
	BCX18		-	-30	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BCX17		-	-45	V
	BCX18		-	-25	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current (DC)		-	-500	mA
I <sub>CM</sub>	peak collector current		-	-1	А
I <sub>BM</sub>	peak base current		-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$ ; note 1	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

### Note

1. Transistor mounted on an FR4 printed-circuit board.

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W	

Note

1. Transistor mounted on an FR4 printed-circuit board.

# BCX17; BCX18

### CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -20 V$	-	—	-100	nA
		$I_E = 0; V_{CB} = -20 \text{ V}; T_j = 150 \text{ °C}$	-	_	-5	μA
I <sub>EBO</sub>	emitter cut-off current	$I_{C} = 0; V_{EB} = -5 V$	-	_	-100	nA
h <sub>FE</sub>	DC current gain	$I_{C} = -100 \text{ mA}; V_{CE} = -1 \text{ V}$	100	_	600	
		$I_{C} = -300 \text{ mA}; V_{CE} = -1 \text{ V}$	70	_	-	
		$I_{C} = -500 \text{ mA}; V_{CE} = -1 \text{ V}$	40	_	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}$	-	_	-620	mV
$V_{BE}$	base-emitter voltage	$I_{C} = -500 \text{ mA}; V_{CE} = -1 \text{ V}; \text{ note } 1$	-	_	-1.2	V
Cc	collector capacitance	$I_E = I_e = 0; V_{CB} = -10 \text{ V}; \text{ f} = 1 \text{ MHz}$	-	9	-	pF
f <sub>T</sub>	transition frequency	$I_{C} = -10 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ f} = 100 \text{ MHz}$	80	_	-	MHz

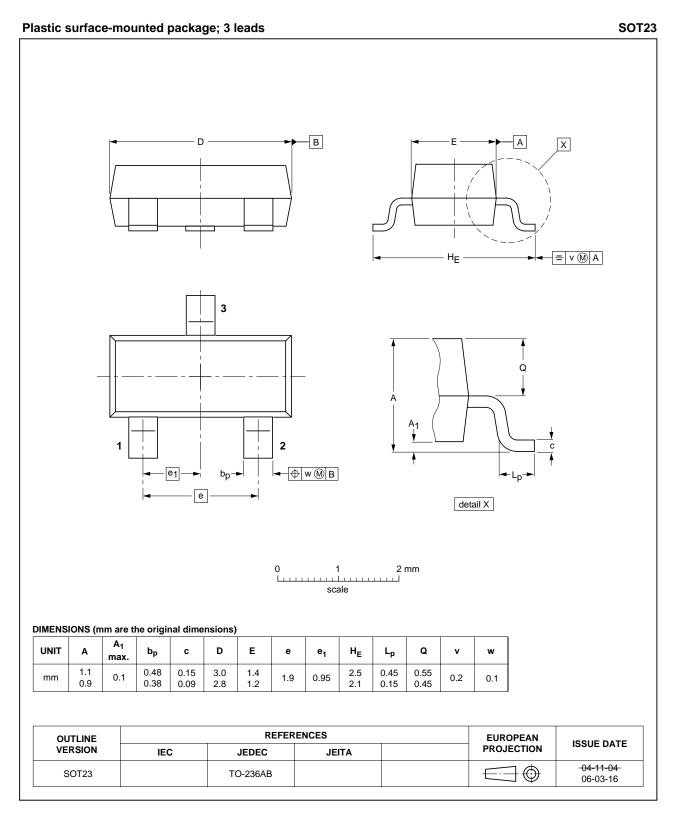
Note

1.  $V_{BE}$  decreases by approximately  $-2 \text{ mV/}^{\circ}\text{C}$  with increasing temperature.

2004 Jan 16

### BCX17; BCX18

### PACKAGE OUTLINE



Downloaded from Arrow.com.

### **BCX17; BCX18**

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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### **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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